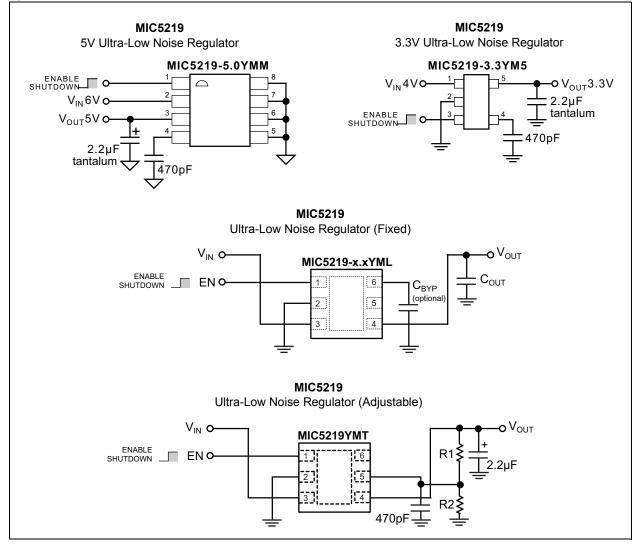
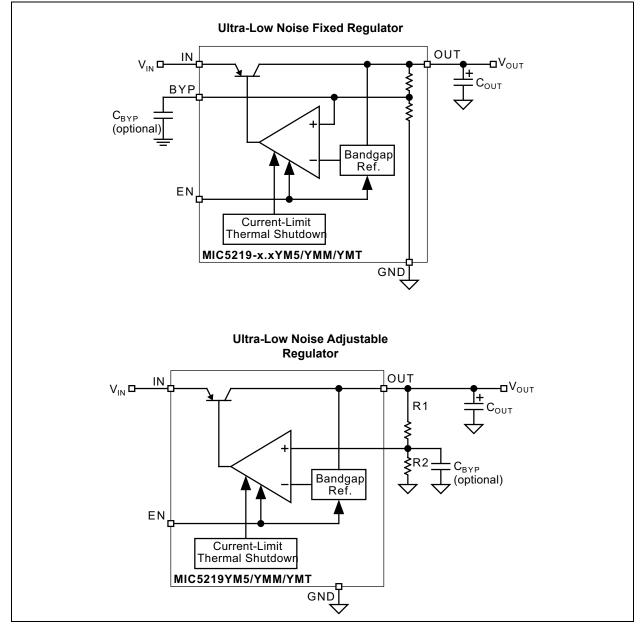


Typical Application Circuits



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Block Diagrams



1.0 ELECTRICAL CHARACTERISTICS

Absolute Maximum Ratings †

Supply Input Voltage (V _{IN})	–20V to +20V
Power Dissipation (P _D)	Internally Limited

Operating Ratings ††

Supply Input Voltage (V _{IN})	+2.5V to +12V
Enable Input Voltage (V _{EN})	0V to V _{IN}

† Notice: Absolute maximum ratings indicate limits beyond which damage to the component may occur. Electrical specifications do not apply when operating the device outside of its operating ratings. The maximum allowable power dissipation is a function of the maximum junction temperature, $T_{J(MAX)}$, the junction-to-ambient thermal resistance, θ_{JA} , and the ambient temperature, T_A . The maximum allowable power dissipation at any ambient temperature is calculated using: $P_{D(MAX)} = (T_{J(MAX)} - T_A) \div \theta_{JA}$. Exceeding the maximum allowable power dissipation will result in excessive die temperature, and the regulator will go into thermal shutdown. See Table 4-1 and the Thermal Considerations section for details.

†† Notice: The device is not guaranteed to function outside its operating rating.

ELECTRICAL CHARACTERISTICS

Electrical Characteristics: Unless otherwise indicated, $V_{IN} = V_{OUT} + 1.0V$; $C_{OUT} = 4.7 \ \mu\text{F}$, $I_{OUT} = 100 \ \mu\text{A}$; $T_J = +25^{\circ}\text{C}$, **bold** values indicate $-40^{\circ}\text{C} \le T_J \le +125^{\circ}\text{C}$.

Parameters	Sym.	Min.	Тур.	Max.	Units	Conditions	
		-1		1	%		
Output Voltage	V _{OUT}	-2	_	2	%	Variation from Nominal V _{OUT}	
Output Voltage Temperature Coefficient	ΔV _{OUT} /ΔT	_	40	—	ppm/°C	Note 1	
Line Degulation			0.009	0.05	0/ 0/		
Line Regulation	ΔV _{OUT} /V _{OUT}			0.1	%/V	$V_{IN} = V_{OUT} + 1V$ to 12V	
Land Danulation		_	0.05	0.5	0/	I _{OUT} = 100 μA to 500 mA,	
Load Regulation	ΔV _{OUT} /V _{OUT}	_		0.7	%	Note 2	

Note 1: Output voltage temperature coefficient is defined as the worst case voltage change divided by the total temperature range.

- **2:** Regulation is measured at constant junction temperature using low duty cycle pulse testing. Parts are tested for load regulation in the load range from 100 μA to 500 mA. Changes in output voltage due to heating effects are covered by the thermal regulation specification.
- **3:** Dropout voltage is defined as the input to output differential at which the output voltage drops 2% below its nominal value measured at 1V differential.
- **4:** Ground pin current is the regulator quiescent current plus pass transistor base current. The total current drawn from the supply is the sum of the load current plus the ground pin current.
- 5: V_{EN} is the voltage externally applied to devices with the EN (enable) input pin.
- 6: Thermal regulation is defined as the change in output voltage at a time "t" after a change in power dissipation is applied, excluding load or line regulation effects. Specifications are for a 500 mA load pulse at V_{IN} = 12V for t = 10 ms.
- 7: C_{BYP} is an optional, external bypass capacitor connected to devices with a BYP (bypass) or ADJ (adjust) pin.

ELECTRICAL CHARACTERISTICS (CONTINUED)

Electrical Characteristics: Unless otherwise indicated, $V_{IN} = V_{OUT} + 1.0V$; $C_{OUT} = 4.7 \ \mu\text{F}$, $I_{OUT} = 100 \ \mu\text{A}$; $T_J = +25^{\circ}\text{C}$, **bold** values indicate $-40^{\circ}\text{C} \le T_J \le +125^{\circ}\text{C}$.

Parameters	Sym.	Min.	Тур.	Max.	Units	Conditions
		_	10	60		1 100 1
		_		80	mV	Ι _{ΟUT} = 100 μΑ
		_	115	175		50 0
		_		250	mV	I _{OUT} = 50 mA
Dropout Voltage (Note 3)	$V_{IN} - V_{OUT}$	_	175	300		450
		_		400	mV	I _{OUT} = 150 mA
		_	350	500		L 500 m A
		_		600	mV	I _{OUT} = 500 mA
		_	80	130		
	I _{GND}	_		170	μA	V _{EN} ≥ 3.0V, I _{OUT} = 100 µA
			350	650	μA	1/2 > 2 0 1/1 = 50 m A
Ground Pin Current		_		900		V _{EN} ≥ 3.0V, I _{OUT} = 50 mA
(Note 4, 5)		_	1.8	2.5		V > 0.0V/ 1
		_		3.0	mA	V _{EN} ≥ 3.0V, I _{OUT} = 150 mA
		_	12	20		V _{EN} ≥ 3.0V, I _{OUT} = 500 mA
		_		25	mA	
Ground Pin Quiescent		_	0.05	3	μA	V _{EN} ≤ 0.4V
Current (Note 4)		_	0.10	8	μA	V _{EN} ≤ 0.18V
Ripple Rejection	PSRR	_	75	_	dB	f = 120 Hz
Current Limit	I _{LIMIT}	_	700	1000	mA	V _{OUT} = 0V
Thermal Regulation (Note 3)	$\Delta V_{OUT} / \Delta P_D$		0.05	_	%/W	Note 6
Output Naiss (Nata 7)		_	500	_	nV/√ Hz	I _{OUT} = 50 mA, C _{OUT} = 2.2 μF, C _{BYP} = 0
Output Noise (Note 7)	e _{no}	_	300	_	nV/√ Hz	I _{OUT} = 50 mA, C _{OUT} = 2.2 μF, C _{BYP} = 470 pF

Note 1: Output voltage temperature coefficient is defined as the worst case voltage change divided by the total temperature range.

- **2:** Regulation is measured at constant junction temperature using low duty cycle pulse testing. Parts are tested for load regulation in the load range from 100 μA to 500 mA. Changes in output voltage due to heating effects are covered by the thermal regulation specification.
- **3:** Dropout voltage is defined as the input to output differential at which the output voltage drops 2% below its nominal value measured at 1V differential.
- **4:** Ground pin current is the regulator quiescent current plus pass transistor base current. The total current drawn from the supply is the sum of the load current plus the ground pin current.
- 5: V_{EN} is the voltage externally applied to devices with the EN (enable) input pin.
- 6: Thermal regulation is defined as the change in output voltage at a time "t" after a change in power dissipation is applied, excluding load or line regulation effects. Specifications are for a 500 mA load pulse at V_{IN} = 12V for t = 10 ms.
- 7: C_{BYP} is an optional, external bypass capacitor connected to devices with a BYP (bypass) or ADJ (adjust) pin.

ELECTRICAL CHARACTERISTICS (CONTINUED)

Electrical Characteristics: Unless otherwise indicated, $V_{IN} = V_{OUT} + 1.0V$; $C_{OUT} = 4.7 \ \mu\text{F}$, $I_{OUT} = 100 \ \mu\text{A}$; $T_J = +25^{\circ}\text{C}$, **bold** values indicate $-40^{\circ}\text{C} \le T_J \le +125^{\circ}\text{C}$.

Parameters Sym.		Min.	Тур.	Max.	Units	Conditions	
ENABLE Input							
		_	_	0.4	v	V _{EN} = logic low (regulator	
Enable Input Logic-Low Voltage	V _{ENL}	_		0.18	v	shutdown)	
		2.0	_	_	V	V _{EN} = logic high (regulator enabled)	
	I _{ENL}	_	0.01	-1	μA	V _{ENL} ≤ 0.4V	
Enable Innut Current			0.01	-2		V _{ENL} ≤ 0.18V	
Enable Input Current		2	5	20			
	IENH	_	_	25	μA	V _{ENH} ≥ 2.0V	

Note 1: Output voltage temperature coefficient is defined as the worst case voltage change divided by the total temperature range.

- **2:** Regulation is measured at constant junction temperature using low duty cycle pulse testing. Parts are tested for load regulation in the load range from 100 μA to 500 mA. Changes in output voltage due to heating effects are covered by the thermal regulation specification.
- **3:** Dropout voltage is defined as the input to output differential at which the output voltage drops 2% below its nominal value measured at 1V differential.
- **4:** Ground pin current is the regulator quiescent current plus pass transistor base current. The total current drawn from the supply is the sum of the load current plus the ground pin current.
- 5: V_{EN} is the voltage externally applied to devices with the EN (enable) input pin.
- 6: Thermal regulation is defined as the change in output voltage at a time "t" after a change in power dissipation is applied, excluding load or line regulation effects. Specifications are for a 500 mA load pulse at V_{IN} = 12V for t = 10 ms.
- 7: C_{BYP} is an optional, external bypass capacitor connected to devices with a BYP (bypass) or ADJ (adjust) pin.

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TEMPERATURE SPECIFICATIONS (Note 1)

Parameters	Sym.	Min.	Тур.	Max.	Units	Conditions	
Temperature Ranges							
Operating Ambient Temperature Range	Τ _Α	-40		+125	°C	—	
Maximum Junction Temperature Range	ТJ	-40		+125	°C	—	
Storage Temperature Range	Τ _S	-65		+150	°C	—	
Lead Temperature	_		260	_	°C	Soldering, 5 sec.	
Package Thermal Resistances							
Thermal Resistance, MSOP-8Ld	θ_{JA}		160	_	°C/W	Minimum footprint area.	
Thermal Resistance, SOT23-5Ld	θ_{JA}		220	_	°C/W	Minimum footprint area.	
Thermal Resistance, VDFN-6Ld	θ_{JA}		90	_	°C/W	Minimum footprint area.	
Thermal Resistance, TDFN-6Ld	θ_{JA}		90	_	°C/W	Minimum footprint area.	

Note 1: The maximum allowable power dissipation is a function of ambient temperature, the maximum allowable junction temperature and the thermal resistance from junction to air (i.e., T_A, T_J, θ_{JA}). Exceeding the maximum allowable power dissipation will cause the device operating junction temperature to exceed the maximum +125°C rating. Sustained junction temperatures above +125°C can impact the device reliability.

2.0 TYPICAL PERFORMANCE CURVES

Note: The graphs and tables provided following this note are a statistical summary based on a limited number of samples and are provided for informational purposes only. The performance characteristics listed herein are not tested or guaranteed. In some graphs or tables, the data presented may be outside the specified operating range (e.g., outside specified power supply range) and therefore outside the warranted range.

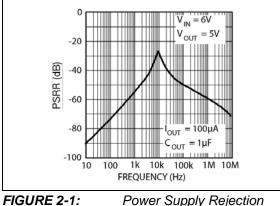


FIGURE 2-1: Ratio.

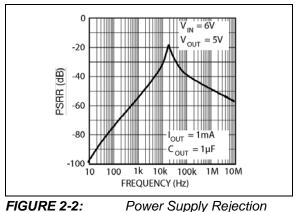
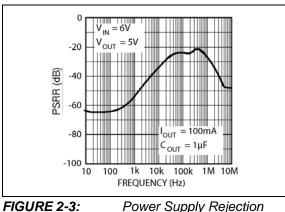


FIGURE 2-2: Ratio.



Ratio.

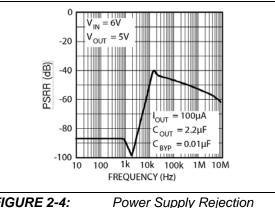


FIGURE 2-4: F Ratio.

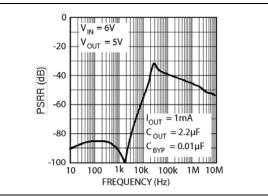


FIGURE 2-5: F

Power Supply Rejection

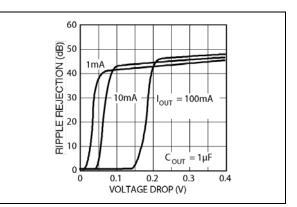


FIGURE 2-6: Power Supply Ripple Rejection vs. Voltage Drop.

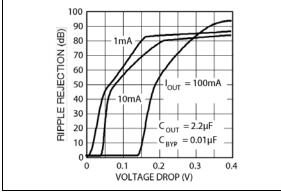


FIGURE 2-7: Power Supply Ripple Rejection vs. Voltage Drop.

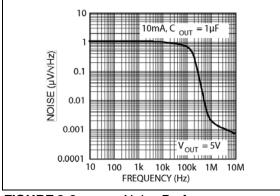


FIGURE 2-8:

Noise Performance.

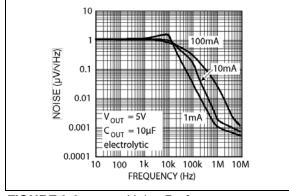


FIGURE 2-9:

Noise Performance.

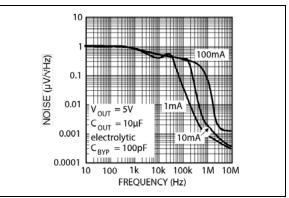


FIGURE 2-10: Noise Performance.

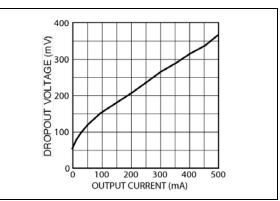


FIGURE 2-11: Dropout Voltage vs. Output Current.

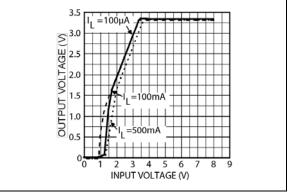


FIGURE 2-12: Dropout Characteristics.

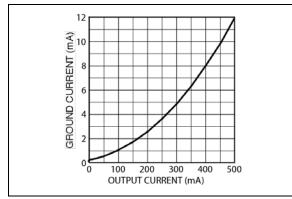


FIGURE 2-13: Ground Current vs. Output Current.

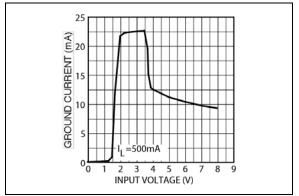


FIGURE 2-14: Ground Current vs. Supply Voltage.

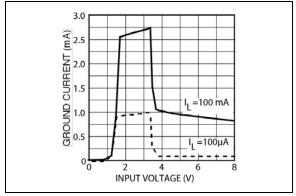


FIGURE 2-15: Ground Current vs. Supply Voltage.

3.0 PIN DESCRIPTIONS

The descriptions of the pins are listed in Table 3-1.

TABLE 3-1: PIN FUNCTION TABLE

Pin Number VDFN-6 TDFN-6	Pin Number MSOP-8	Pin Number SOT23-5	Pin Name	Description
3	2	1	IN	Supply input.
2	5 - 8	2	GND	Ground: MSOP-8 pins 5 through 8 are internally con- nected.
4	3	5	OUT	Regulator output.
1	1	3	EN	Enable (input): CMOS-compatible control input. Logic-high = enable; logic-low or open = shutdown.
6	4 (FIXED)	4 (FIXED)	BYP	Reference bypass: Connect an external 470 pF capacitor to GND to reduce output noise. May be left open.
5 (NC)	4 (ADJ)	4 (ADJ)	ADJ	Adjust (input): Feedback input. Connect to resistive volt- age-divider network.
EP	_	_	GND	Ground: Internally connected to the exposed pad. Con- nect externally to GND pin.

4.0 APPLICATION INFORMATION

The MIC5219 is designed for 150 mA to 200 mA output current applications where a high-current spike (500 mA) is needed for short, start-up conditions. Basic application of the device will be discussed initially followed by a more detailed discussion of higher current applications.

4.1 Enable/Shutdown

Forcing EN (enable/shutdown) high (>2V) enables the regulator. EN is compatible with CMOS logic. If the enable/shutdown feature is not required, connect EN to IN (supply input). See Figure 4-5.

4.2 Input Capacitor

A 1 μ F capacitor should be placed from IN to GND if there is more than 10 inches of wire between the input and the AC filter capacitor or if a battery is used as the input.

4.3 Output Capacitor

An output capacitor is required between OUT and GND to prevent oscillation. The minimum size of the output capacitor is dependent upon whether a reference bypass capacitor is used. 1 μ F minimum is recommended when C_{BYP} is not used (see Figure 4-5). 2.2 μ F minimum is recommended when C_{BYP} is 470 pF (see Figure 4-6). For applications <3V, the output capacitor should be increased to 22 μ F minimum to reduce start-up overshoot. Larger values improve the regulator's transient response. The output capacitor value may be increased without limit.

The output capacitor should have an ESR (equivalent series resistance) of about 1Ω or less and a resonant frequency above 1 MHz. Ultra-low ESR capacitors could cause oscillation and/or under-damped transient response. Most tantalum or aluminum electrolytic capacitors are adequate; film types will work, but are more expensive. Many aluminum electrolytics have electrolytes that freeze at about -30° C, so solid tantalums are recommended for operation below -25° C.

At lower values of output current, less output capacitance is needed for stability. The capacitor can be reduced to 0.47 μ F for current below 10 mA, or 0.33 μ F for currents below 1 mA.

4.4 No-Load Stability

The MIC5219 will remain stable and in regulation with no load (other than the internal voltage divider) unlike many other voltage regulators. This is especially important in CMOS RAM keep-alive applications.

4.5 Reference Bypass Capacitor

BYP is connected to the internal voltage reference. A 470 pF capacitor (C_{BYP}) connected from BYP to GND quiets this reference, providing a significant reduction in output noise (ultra-low noise performance). C_{BYP} reduces the regulator phase margin; when using C_{BYP} , output capacitors of 2.2 μ F or greater are generally required to maintain stability.

The start-up speed of the MIC5219 is inversely proportional to the size of the reference bypass capacitor. Applications requiring a slow ramp-up of output voltage should consider larger values of C_{BYP} . Likewise, if rapid turn-on is necessary, consider omitting C_{BYP} .

4.6 Thermal Considerations

The MIC5219 is designed to provide 200 mA of continuous current in two very small profile packages. Maximum power dissipation can be calculated based on the output current and the voltage drop across the part. To determine the maximum power dissipation of the package, use the thermal resistance, junction-to-ambient, of the device and the following basic equation.

EQUATION 4-1:

$$P_{D(MAX)} = \frac{T_{J(MAX)} - T_A}{\theta_{JA}}$$

 $T_{J(MAX)}$ is the maximum junction temperature of the die, +125°C, and T_A is the ambient operating temperature. θ_{JA} is layout-dependent; Table 4-1 shows examples of thermal resistance, junction-to-ambient, for the MIC5219.

TABLE 4-1:	MIC5219 THERMAL
	RESISTANCE

Package	θ _{JA} Rec. Min. Footprint	θ _{JA} 1" Square 2 oz. Copper	θ _{JC}				
MSOP-8	160°C/W	70°C/W	30°C/W				
SOT23-5	220°C/W	170°C/W	130°C/W				
2x2 VDFN	90°C/W	—	_				
2x2TDFN	90°C/W	—	_				

The actual power dissipation of the regulator circuit can be determined using one simple equation.

EQUATION 4-2:

$$P_D = (V_{IN} - V_{OUT}) \times I_{OUT} + V_{IN} \times I_{GND}$$

Substituting $P_{D(MAX)}$ for P_D and solving for the operating conditions that are critical to the application will give the maximum operating conditions for the regulator circuit. For example, if we are operating the MIC5219-3.3YM5 at room temperature, with a minimum footprint layout, we can determine the maximum input voltage for a set output current.

EQUATION 4-3:

$$P_{D(MAX)} = \frac{125^{\circ}C - 25^{\circ}C}{220^{\circ}C/W} = 455mW$$

The thermal resistance, junction-to-ambient, for the minimum footprint is 220°C/W, taken from Table 4-1. The maximum power dissipation number cannot be exceeded for proper operation of the device. Using the output voltage of 3.3V, and an output current of 150 mA, we can determine the maximum input voltage. Ground current, maximum of 3 mA for 150 mA of output current, can be taken from the Electrical Characteristics section of the data sheet.

EQUATION 4-4:

$$455mW = (V_{IN} - 3.3V) \times 150mA + V_{IN} \times 3mA$$
$$455mW = 150mA \times V_{IN} + 3mA \times V_{IN} - 495mW$$
$$950mW = 153mA \times V_{IN}$$
$$V_{IN(MAX)} = 6.2V_{MAX}$$

Therefore, a 3.3V application at 150 mA of output current can accept a maximum input voltage of 6.2V in a SOT23-5 package. For a full discussion of heat sinking and thermal effects on voltage regulators, refer to the "Regulator Thermals" section of Microchip's Designing with Low-Dropout Voltage Regulators handbook.

4.7 Peak Current Applications

The MIC5219 is designed for applications where high start-up currents are demanded from space constrained regulators. This device will deliver 500 mA start-up current from a SOT23-5 or MSOP-8 package, allowing high power from a very low profile device. The MIC5219 can subsequently provide output current that is only limited by the thermal characteristics of the device. You can obtain higher continuous currents from the device with the proper design. This is easily proved with some thermal calculations.

If we look at a specific example, it may be easier to follow. The MIC5219 can be used to provide up to 500 mA continuous output current. First, calculate the maximum power dissipation of the device, as was done in the Thermal Considerations section. Worst case thermal resistance ($\theta_{JA} = 220^{\circ}$ C/W for the MIC5219-x.xYM5), will be used for this example.

EQUATION 4-5:

$$P_{D(MAX)} = \frac{T_{J(MAX)} - T_A}{\theta_{JA}}$$

Assuming a 25°C room temperature, we have a maximum power dissipation value calculated in Equation 4-6.

$$P_{D(MAX)} = \frac{125^{\circ}C - 25^{\circ}C}{220^{\circ}C/W} = 455mW$$

Then we can determine the maximum input voltage for a 5 volt regulator operating at 500 mA, using worst case ground current.

EQUATION 4-7:

 $P_{D(MAX)} = 455mW =$ $(V_{IN} - V_{OUT}) \times I_{OUT} + V_{IN} \times I_{GND}$ Where: $I_{OUT} = 500 \text{ mA}$ $V_{OUT} = 5V$ $I_{GND} = 20 \text{ mA}$ $455mW = (V_{IN} - 5V) \times 500mA + V_{IN} \times 20mA$ $2.995W = 520mA \times V_{IN}$ $V_{IN(MAX)} = \frac{2.995W}{520mA} = 5.683V$

Therefore, to be able to obtain a constant 500 mA output current from the MIC5219-5.0YM5 at room temperature, you need extremely tight input-output voltage differential, barely above the maximum dropout voltage for that current rating.

You can run the part from larger supply voltages if the proper precautions are taken. Varying the duty cycle using the enable pin can increase the power dissipation of the device by maintaining a lower average power figure. This is ideal for applications where high current is only needed in short bursts. Figure 4-1 shows the safe operating regions for the MIC5219-x.xYM5 at three different ambient temperatures and at different

output currents. The data used to determine this figure assumed a minimum footprint PCB design for minimum heat sinking. Figure 4-2 incorporates the same factors as the first figure, but assumes a much better heat sink. A 1" square copper trace on the PC board reduces the thermal resistance of the device. This improved thermal resistance improves power dissipation and allows for a larger safe operating region.

Figure 4-3 and Figure 4-4 show safe operating regions for the MIC5219-x.xYMM, the power MSOP package part. These graphs show three typical operating regions at different temperatures. The lower the temperature, the larger the operating region. The graphs were obtained in a similar way to the graphs for the MIC5219-x.xYM5, taking all factors into consideration and using two different board layouts, minimum footprint and 1" square copper PC board heat sink. For further discussion of PC board heat sink characteristics, refer to Application Hint 17, Designing PC Board Heat Sinks.

The information used to determine the safe operating regions can be obtained in a similar manner such as determining typical power dissipation, already discussed. Determining the maximum power dissipation based on the layout is the first step, this is

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done in the same manner as in the previous two sections. Then, a larger power dissipation number multiplied by a set maximum duty cycle would give that maximum power dissipation number for the layout. This is best shown through an example. If the application calls for 5V at 500 mA for short pulses, but the only supply voltage available is 8V, then the duty cycle has to be adjusted to determine an average power that does not exceed the maximum power dissipation for the layout.

EQUATION 4-8:

$$Av \dot{g} P_D = \left(\frac{\% \text{DC}}{100}\right) (V_{IN} - V_{OUT}) \times I_{OUT} + V_{IN} \times I_{GND}$$

$$455mW = \left(\frac{\% \text{DC}}{100}\right) (8V - 5V) \times 500mA + 8V \times 20mA$$

$$455mW = \left(\frac{\% \text{DC}}{100}\right) \times 1.66W$$

$$0.274 = \frac{\% \text{DC}}{100}$$

$$\% \text{DC} = 27.4\% (\text{Duty Cycle Max.})$$

With an output current of 500 mA and a three volt drop across the MIC5219-xxYMM, the maximum duty cycle is 27.4%.

Applications also call for a set nominal current output with a greater amount of current needed for short durations. This is a tricky situation, but it is easily remedied. Calculate the average power dissipation for each current section, then add the two numbers giving the total power dissipation for the regulator. For example, if the regulator is operating normally at 50 mA, but for 12.5% of the time it operates at 500 mA output, the total power dissipation of the part can be easily determined. First, calculate the power dissipation of the device at 50 mA. We will use the MIC5219-3.3YM5 with 5V input voltage as our example.

EQUATION 4-9:

$$P_D \times 50mA = (5V - 3.3V) \times 50mA + 5V \times 650\mu A$$

 $P_D \times 50mA = 88.25mW$

However, this is continuous power dissipation, the actual on-time for the device at 50 mA is (100% - 12.5%) or 87.5% of the time, or 87.5% duty cycle. Therefore, P_D must be multiplied by the duty cycle to obtain the actual average power dissipation at 50 mA.

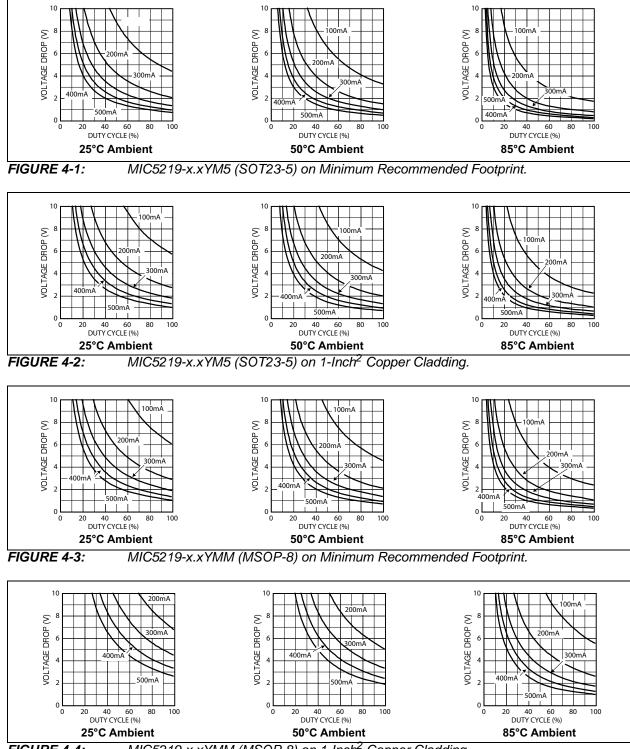


FIGURE 4-4: MIC5219-x.xYMM (MSOP-8) on 1-Inch² Copper Cladding.

EQUATION 4-10:

$$P_D \times 50mA = 0.875 \times 88.25mW$$
$$P_D \times 50mA = 77.22mW$$

The power dissipation at 500 mA must also be calculated.

EQUATION 4-11:

$$P_D \times 500mA = (5V - 3.3V) \times 500mA + 5V \times 20mA$$
$$P_D \times 500mA = 950mW$$

This number must be multiplied by the duty cycle at which it would be operating: 12.5%.

EQUATION 4-12:

$$P_D = 0.125 \times 950 mW$$
$$P_D = 118.75 mW$$

The total power dissipation of the device under these conditions is the sum of the two power dissipation figures.

EQUATION 4-13:

$$P_{D(TOTAL)} = P_D \times 50mA + P_D \times 500mA$$
$$P_{D(TOTAL)} = 77.22mW + 118.75mW$$
$$P_{D(TOTAL)} = 196mW$$

The total power dissipation of the regulator is less than the maximum power dissipation of the SOT23-5 package at room temperature, on a minimum footprint board and therefore would operate properly.

Multilayer boards with a ground plane, wide traces near the pads, and large supply-bus lines will have better thermal conductivity.

For additional heat sink characteristics, please refer to Application Hint 17, Designing P.C. Board Heat Sinks. For a full discussion of heat sinking and thermal effects on voltage regulators, refer to "Regulator Thermals" section of Microchip's Designing with Low-Dropout Voltage Regulators handbook.

4.8 Fixed Regulator Circuits

Figure 4-5 shows a basic MIC5219-x.xYMX fixed-voltage regulator circuit. A 1μ F minimum output capacitor is required for basic fixed-voltage applications.

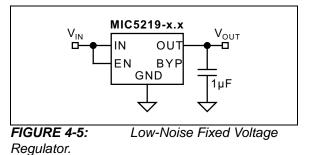


Figure 4-6 includes the optional 470 pF noise bypass capacitor between BYP and GND to reduce output noise. Note that the minimum value of C_{OUT} must be increased when the bypass capacitor is used.

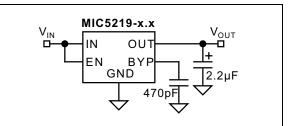


FIGURE 4-6: Ultra-Low Noise Fixed Voltage Regulator.

4.9 Adjustable Regulator Circuits

Figure 4-7 shows the basic circuit for the MIC5219 adjustable regulator. The output voltage is configured by selecting values for R1 and R2 using the following formula.

EQUATION 4-14:

$$V_{OUT} = 1.242 V \times \left(\frac{R2}{R1} + 1\right)$$

This equation is correct due to the configuration of the bandgap reference. The bandgap voltage is relative to the output, as seen in the block diagram. Traditional regulators normally have the reference voltage relative to ground and have a different V_{OUT} equation.

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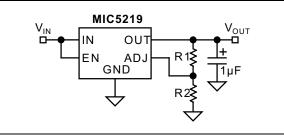


FIGURE 4-7: Low-Noise Adjustable Voltage Regulator.

Although ADJ is a high-impedance input, for best performance, R2 should not exceed 470 k Ω .

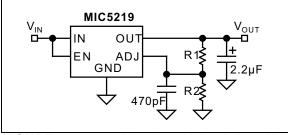
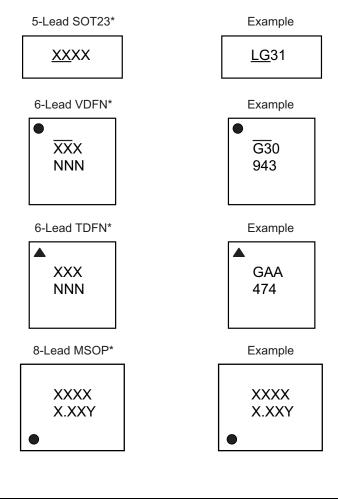


FIGURE 4-8: Ultra-Low Noise Adjustable Application.

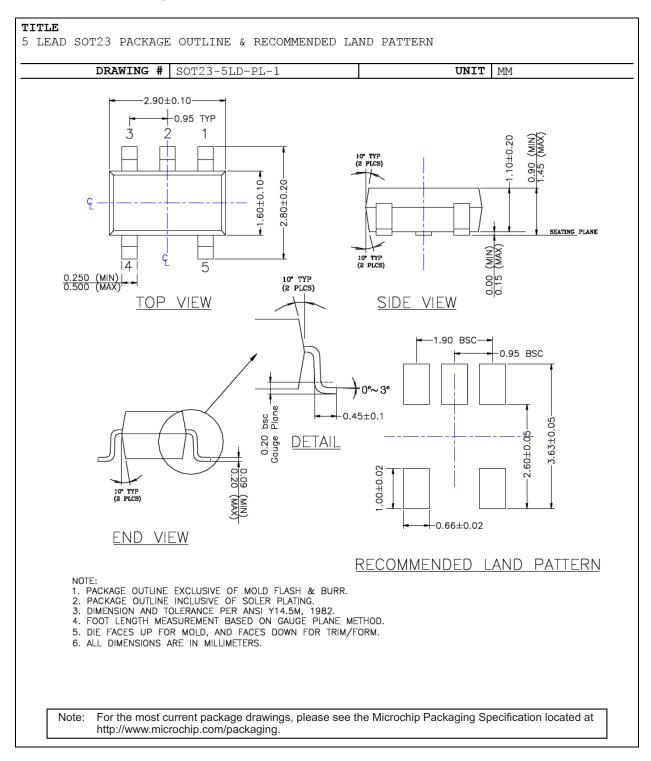
Figure 4-8 includes the optional 470 pF bypass capacitor from ADJ to GND to reduce output noise.

5.0 PACKAGING INFORMATION

5.1 Package Marking Information

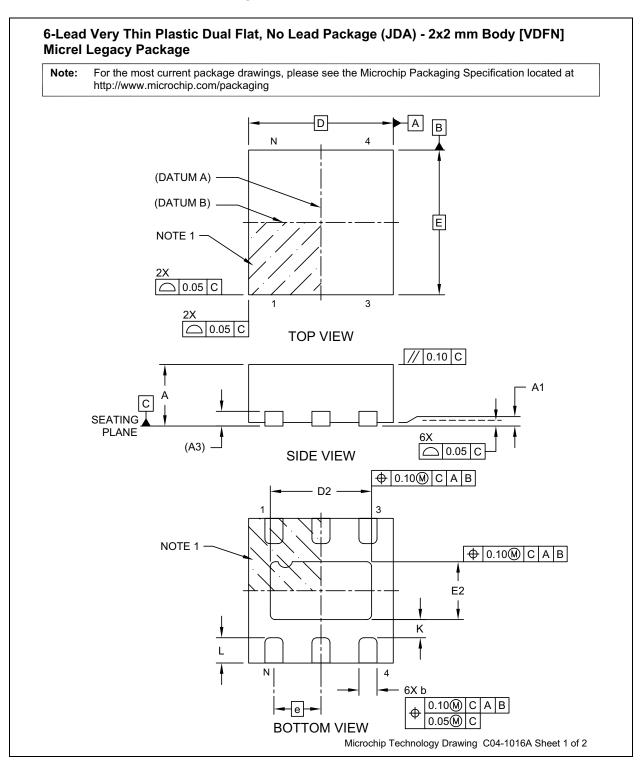


Legend:	Y YY WW NNN @3 *	Product code or customer-specific information Year code (last digit of calendar year) Year code (last 2 digits of calendar year) Week code (week of January 1 is week '01') Alphanumeric traceability code Pb-free JEDEC [®] designator for Matte Tin (Sn) This package is Pb-free. The Pb-free JEDEC designator (e3) can be found on the outer packaging for this package.				
t de la constante de la consta	mark). E: In the event the full Microchip part number cannot be marked on one line, it will be carried over to the next line, thus limiting the number of available characters for customer-specific information. Package may or may not include the corporate logo. Underbar (_) and/or Overbar (⁻) symbol may not be to scale.					

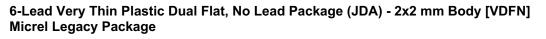


5-Lead SOT23 Package Outline and Recommended Land Pattern

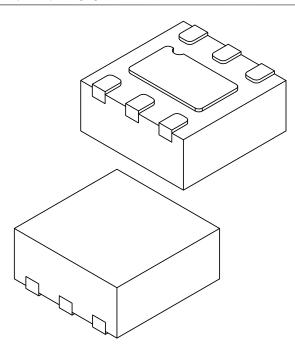
6-Lead VDFN 2 mm x 2 mm Package Outline and Recommended Land Pattern



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Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



	Units	1	MILLIMETER	S
Dimens	sion Limits	MIN	NOM	MAX
Number of Terminals	Ν		6	
Pitch	е		0.65 BSC	
Overall Height	Α	0.80	0.85	0.90
Standoff	A1	0.00	0.02	0.05
Terminal Thickness	A3	0.203 REF		
Overall Length	D		2.00 BSC	
Exposed Pad Length	D2	1.35	1.40	1.45
Overall Width	E		2.00 BSC	
Exposed Pad Width	E2	0.75	0.80	0.85
Terminal Width	b	0.20	0.25	0.30
Terminal Length	L	0.30	0.35	0.40
Terminal-to-Exposed-Pad	K	0.20	-	-

Notes:

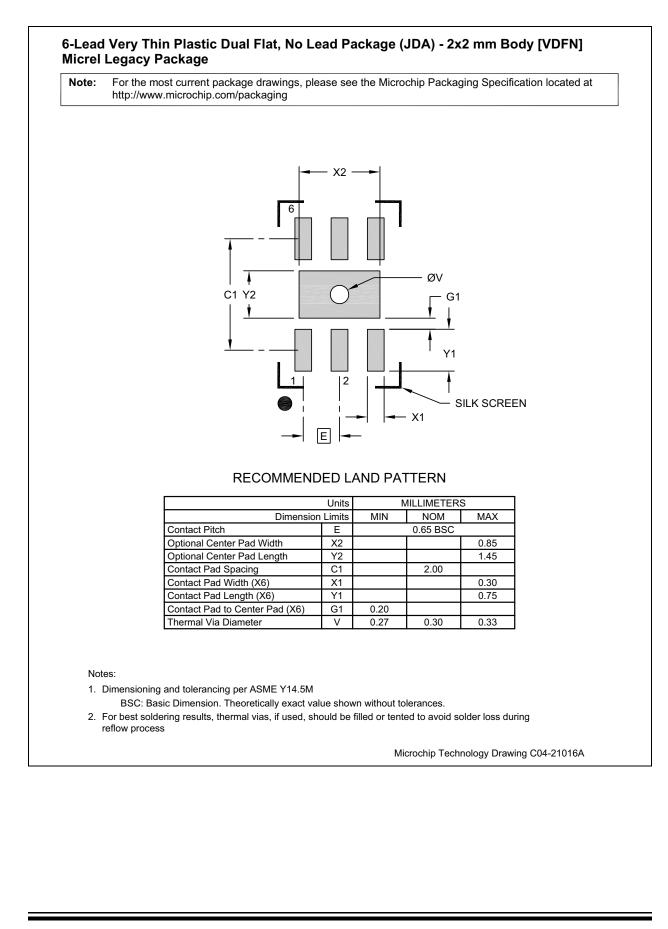
1. Pin 1 visual index feature may vary, but must be located within the hatched area.

2. Package is saw singulated

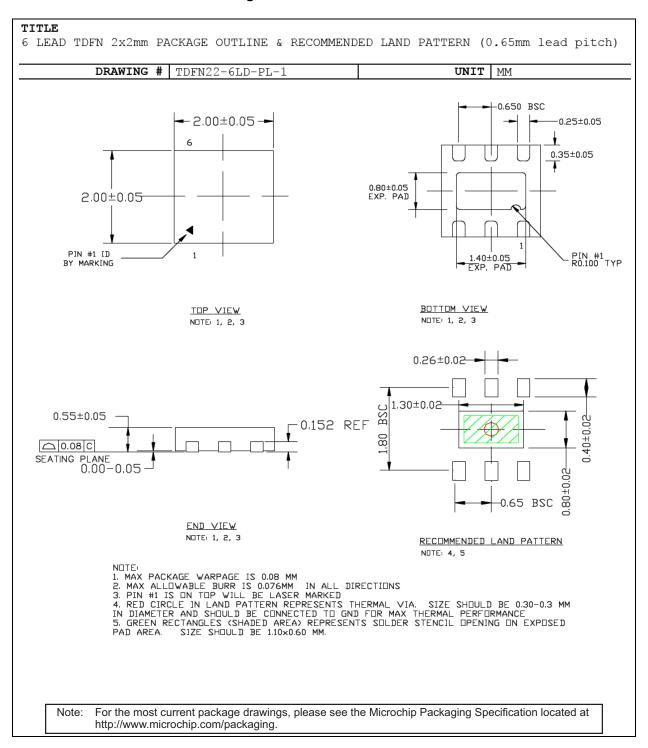
3. Dimensioning and tolerancing per ASME Y14.5M

BSC: Basic Dimension. Theoretically exact value shown without tolerances. REF: Reference Dimension, usually without tolerance, for information purposes only.

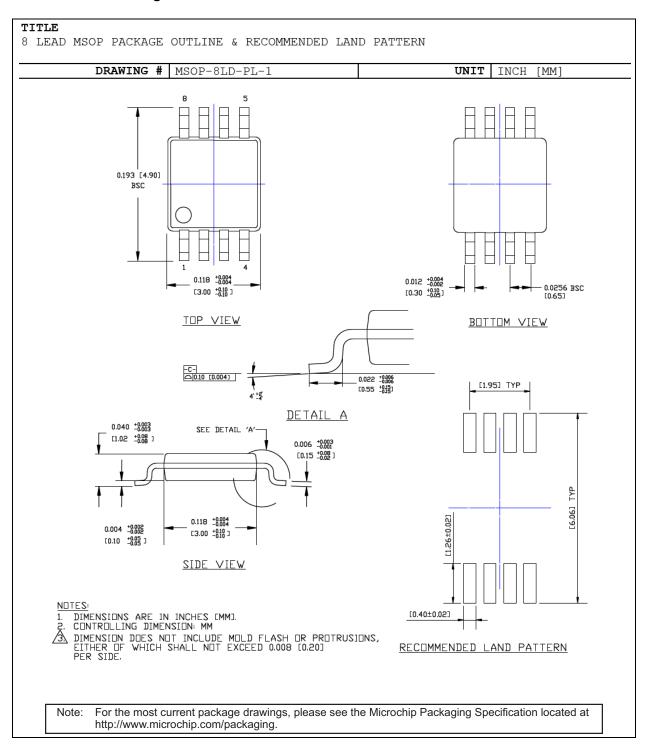
Microchip Technology Drawing C04-1016A Sheet 2 of 2



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6-Lead 2 mm x 2 mm TDFN Package Outline and Recommended Land Pattern



8-Lead MSOP Package Outline and Recommended Land Pattern

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MIC5219

NOTES:

APPENDIX A: REVISION HISTORY

Revision A (May 2018)

- Converted Micrel document MIC5219 to Microchip data sheet DS20006021A.
- Minor text changes throughout.

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MIC5219

NOTES:

PRODUCT IDENTIFICATION SYSTEM

To order or obtain information, e.g., on pricing or delivery, contact your local Microchip representative or sales office.

					Examples:
Device	<u>X.X</u>	<u>x</u>	<u>XX</u>	- <u>XX</u>	a) 5-Lead SOT23, 500 mA Peak Output Current Capability,
Part No.	Voltage	Junction	Package	Media Type	Adjustable & Fixed Output Voltages, 3,000/Reel.
Device:	MIC5219:	Temp. Range 500 mA Pea	k Output LDO R	egulator	Catalog P/N Output Voltage Marking Code MIC5219-2.5YM5-TR 2.5V LG25 MIC5219-2.6YM5-TR 2.6V LG26 MIC5219-2.7YM5-TR 2.7V LG27 MIC5209-2.0YM5-TR 2.0V LG27
Voltage:	2.5 = 2.6 = 2.7 = 2.8 = 2.85 = 2.9 = 3.0 = 3.1 = 3.3 = 3.6 =	2.5V (SOT23, MSC 2.6V (SOT23 Pack 2.7V (SOT23 Pack 2.8V (VDFN Packa 2.85V (SOT23, MS 2.9V (SOT23, MSC 3.0V (SOT23, MSC 3.1V (SOT23, MSC 3.6V (SOT23, MSC 3.6V (SOT23, MSC 5.6V (SOT23, MSC	age) age) (OP Packages) age) DP, VDFN Packa age) DP, VDFN Packa DP Packages)	ages)	MIC5219-2.8YM5-TR 2.8V LG28 MIC5219-2.85YM5-TR 2.85V LG2J MIC5219-2.9YM5-TR 2.9V LG29 MIC5219-3.0YM5-TR 3.0V LG30 MIC5219-3.1YM5-TR 3.1V LG31 MIC5219-3.3YM5-TR 3.3V LG33 MIC5219-3.6YM5-TR 3.6V LG36 MIC5219-5.0YM5-TR 5.0V LG50 MIC5219-5.0YM5-TR Adjustable b) b) 6-Lead VDFN, 500 mA Continuous Output Current Capability, Adjustable & Fixed Output Voltages, 5,000/Reel Current Capability, Adjustable & Fixed Output Voltages, 5,000/Reel
Junction Temperature Range:	5.0 = <blank>= Y =</blank>	5.0V (SOT23, MSC ADJ (SOT23, MSC -40°C to +125°C			Catalog P/N Output Voltage Marking Code MIC5219-2.8YML-TR 2.8V <u>G</u> 28 MIC5219-3.0YML-TR 3.0V <u>G</u> 30 MIC5219-3.3YML-TR 3.3V <u>G</u> 33 MIC5219-3.6YML-TR 3.6V <u>G</u> 36
Package:	M5 = ML = MT = MM =	5-Lead SOT23 6-Lead 2 mm x 2 n 6-Lead 2 mm x 2 n 8-Lead MSOP			c) 6-Lead TDFN, 500 mA Continuous Output Current Capability, Adjustable & Fixed Output Voltages, 5,000/Reel Catalog P/N Output Voltage Marking Code MIC5219-5.0YMT-TR 5.0V G50 MIC5219YMT-TR Adjustable GAA
Media Type:		3,000/Reel (SOT2: 3,000/Reel (SOT2: 2,500/Reel (MSOP 5,000/Reel (VDFN 100/Tube (MSOP)	3 Reverse Pin 1) and TDFN)		d) 8-Lead MSOP, 500 mA Continuous Output Current Capability, Adjustable & Fixed Output Voltages, 100/Tube or 2,500/Reel <u>CPN Bulk</u> <u>Qty</u> <u>CPN T/R</u> Qty MIC5219-2.5YMM 100/Tube MIC5219-2.5YMM-TR 2,500/Reel 2,500/Reel MIC5219-3.6YMM 100/Tube MIC5219-3.6YMM-TR 2,500/Reel MIC5219-3.0YMM 100/Tube MIC5219-3.0YMM-TR 2,500/Reel MIC5219-3.3YMM 100/Tube MIC5219-3.0YMM-TR 2,500/Reel MIC5219-3.3YMM 100/Tube MIC5219-3.3YMM-TR 2,500/Reel MIC5219-3.3YMM 100/Tube MIC5219-3.3YMM-TR 2,500/Reel
Note: Other volta	ige options a	available. Contact y	our Microchip	Sales Office.	MIC5219-5.0YMM 100/Tube MIC5219-5.0YMM-TR 2,500/Reel MIC5219YMM 100/Tube MIC5219YMM-TR 2,500/Reel
					Note 1: Tape and Reel identifier only appears in the catalog part number description. This identifier is used for ordering purposes and is not printed on the device package. Check with your Microchip Sales Office for package availability with the Tape and Reel option.

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